### APPLICATION NOTE

# Charge Carrier Recombination Dynamics of Semiconductor Photocatalysts



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# Introduction

Photo-catalysis, the induction of chemical changes by absorption of light, is crucial for many environmental studies and sought for water splitting and hydrogen production,<sup>1,2</sup> removal of pollutants,<sup>3,4</sup> as well as artificial photosynthesis.<sup>5</sup>

With this wide spread of applications, earth-abundant photocatalysts are attracting extensive interest, especially based on anatase  $\text{TiO}_2$  due to its abundance,<sup>6-8</sup> and low toxicity.<sup>5,9</sup> Due to its wide bandgap at 3.2 eV, however, it is not a good absorber in the visible range. Viable routes to extend its absorption include doping with transition metals to induce defect states in the lattice and tune the bandgap towards the visible.

In this application note, by means of time-resolved photoluminescence spectroscopy, we study the dynamics of charge carriers in copper-nitrogen-titanium oxide (Cu-N- $TiO_2$ ).

# **Methods and Materials**

Time-resolved emission maps were performed in an FLS980 Fluorescence Spectrometer equipped with double excitation and emission monochromators, a photomultiplier tube detector (PMT-900) and a 450 W Xe lamp for steady-state spectral measurements. A Q-switched Nd: YAG laser (Continuum, Minilite) directly coupled to the spectrometer in L geometry was used as excitation in time-resolved measurements. The fundamental frequency of the laser was tripled, generating 355 nm light pulses of 4 ns pulse width at a repetition rate of 10 Hz and irradiance of 18 mW/cm<sup>2</sup>. Gratings blazed at 400 nm were used in the excitation and emission arms, with higher diffraction orders being filtered by the integrated long wave-pass filters in the FLS980.

Thin-films of pure and Cu-N-doped TiO<sub>2</sub> samples were deposited on <100> silicon substrates by radio-frequency (RF) magnetron sputtering. High purity TiO<sub>2</sub> and copper plates were used in a vacuumed deposition chamber under argon atmosphere. For PL measurements, the samples were placed on a front face sample holder utilising 45° orientation, while a 395 nm long-pass filter placed on the sample holder was used to eliminate scattering excitation light.

## **Results-Discussion**

The distinctive decay kinetics of TiO<sub>2</sub> and Cu-N-TiO<sub>2</sub> are evident in the time-resolved emission maps of Figures 1 and 2, respectively. Particularly exciton emission at 410 nm in pure TiO<sub>2</sub> is completely quenched in favour of the Cu-N defect states associated to the nano-columns formed at the surface of the deposited films.<sup>10,11</sup>



Figure 1: Time-resolved emission map of TiO $_{\rm 2}$  sample. The cross section is at 3.20  $\mu s$  and 550 nm.



Figure 2: Time-resolved emission map of sample Cu-N-TiO<sub>2</sub> sample. The cross section isat 3.00  $\mu$ s and 500 nm.

The fit of the decays at 410 nm and 550 nm were directly extracted from the maps of Figures 1 and 2. The long-lived exciton lifetime of pure TiO<sub>2</sub> corresponds to a single exponent of 93 µs, displayed in Figure 3. Although the long-lived emission fits well in an equation of the form  $I_{PL}=I_0e^{-(t/\tau)}$ , the recombination kinetics at 550 nm were better fit to stretched exponentials of the form  $I_{PL}=I_0e^{-(t/\tau)\beta}$ .<sup>11</sup>

Reported TiO<sub>2</sub> lifetimes vary from ns to ms depending on the preparation technique. Preparation techniques vary widely,<sup>12</sup> with chemical vapour deposition (CVD) and RF magnetron sputtering being the most commonly used. While TiO<sub>2</sub> powders of 60 nm to 3 µm crystal size reported 0.04 ns - 1.3 ns and up to 2.4 ns lifetimes in proportion to the crystal size,<sup>13-14</sup> anatase films grown by CVD exhibited lifetimes in the range of 10 µs - 30 µs at room temperature and 77 K.<sup>15,16</sup> Similar lifetimes in the range of 10 µs - 80 µs have been reported for nanostructured semiconductors such as oxidised porous silicon.<sup>10</sup>

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**Figure 3:** Photoluminescence decays of  $TiO_2$  and  $Cu-N-TiO_2$  samples monitored at 410 nm.

The time-resolved emission spectra (TRES) were readily obtained by the time-resolved emission maps in the range 32  $\mu$ s - 40  $\mu$ s in five bins of 2  $\mu$ s width and are plotted in Figures 5 and 6. It can be clearly seen that the emission of the selftrapped exciton inherent in the pure TiO<sub>2</sub> sample is completely quenched in the Cu-N-TiO<sub>2</sub> sample.



**Figure 4:** Photoluminescence decays of  $\text{TiO}_2$  and  $\text{Cu-N-TiO}_2$  samples monitored at 550 nm.



**Figure 5:** Time-resolved emission spectra of  $TiO_2$  sample reconstructed from TRES maps of Figure 1.



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**Figure 6:** Normalised time-resolved emission spectra of Cu-N-TiO<sub>2</sub> sample reconstructed from TRES maps of Figure 2.

In addition to the temporal evolution of the emission spectra that can be investigated, spectra free from artefacts can also be obtained with this technique. Care needs to be taken in the acquisition of excitation and emission spectra of  $TiO_2$  samples, weakly emitting under excitation with standard Xe lamps. As is the case of highly scattering samples such as PTFE, experimental artefacts can be superimposed with the emission of the sample.<sup>17-19</sup> This can be circumvented by the use of appropriately powered lasers as excitation sources, as demonstrated in this application note.

### Conclusions

Charge carrier recombination in thin-films of Cu-N-TiO<sub>2</sub> was presented in this application note. The photoluminescence of the films was characterised by means of time-resolved spectroscopy and revealed the dynamics of charge carriers in TiO<sub>2</sub> by addition of Cu and N. The use of high power pulsed laser sources in conjunction with FLS980 double monochromator fluorescence spectrometers enabled this study, while minimising the manifestation of artefacts commonly evidenced for weakly emitting samples.

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